

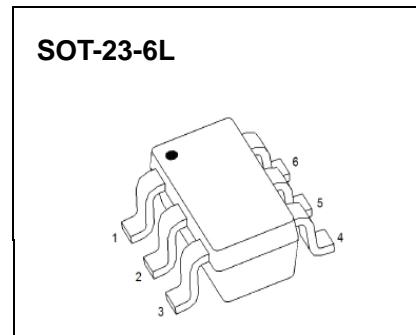


JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOT-23-* L Plastic-Encapsulate MOSFETS

CJ@3415 P-Channel 20V(D-S) MOSFET

| $V_{(BR)DSS}$ | $R_{DS(on)}\text{MAX}$ | I_D |
|---------------|------------------------|-------|
| -20V | 50mΩ@-4.5V | -4.0A |
| | 60mΩ@-2.5V | |
| | 73mΩ@-1.8V | |

**FEATURE**Excellent $R_{DS(\text{ON})}$, low gate charge, low gate voltage

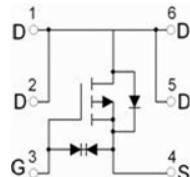
High power and current handing capability

APPLICATION

Load switch and in PWM applicatops.

MARKING:

PIN1

Equivalent Circuit**Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)**

| Parameter | Symbol | Value | Unit |
|---|-----------------|-----------|------|
| Drain-Source Voltage | V_{DS} | -20 | V |
| Gate-Source Voltage | V_{GS} | ±8 | |
| Continuous Drain Current ($t \leq 10\text{s}$) | I_D | -4.0 | A |
| Pulsed Drain Current (note1) | I_{DM} | -30 | A |
| Maximum Power Dissipation ($t \leq 10\text{s}$) | P_D | 0.35 | W |
| Thermal Resistance from Junction to Ambient | $R_{\theta JA}$ | 357 | °C/W |
| Operating Junction Temperature | T_J | 150 | °C |
| Storage Temperature | T_{STG} | -55 ~+150 | °C |

MOSFET ELECTRICAL CHARACTERISTICS

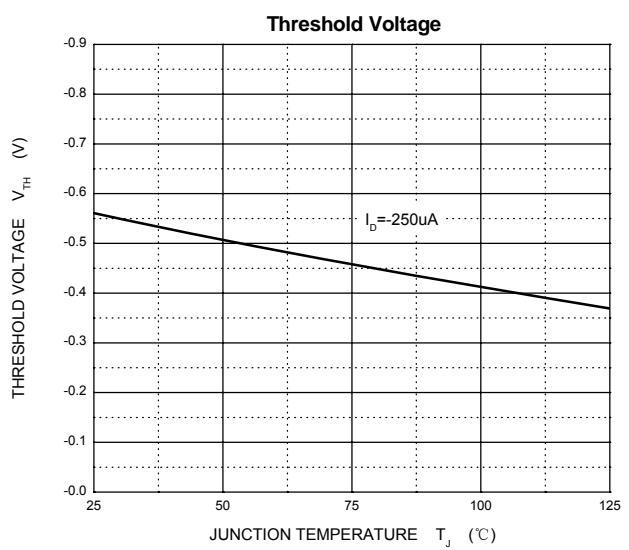
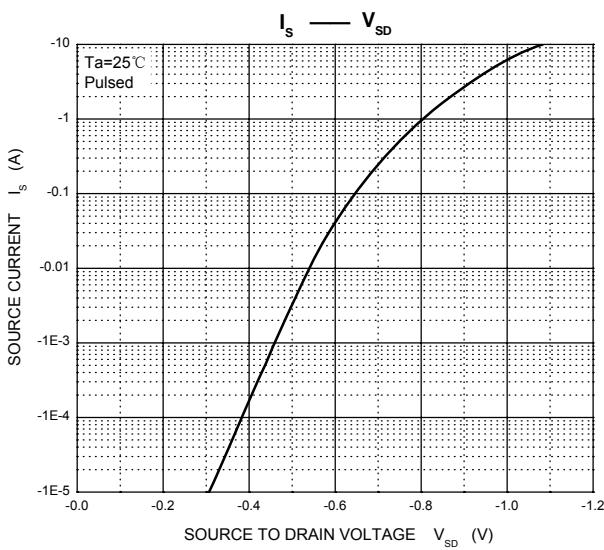
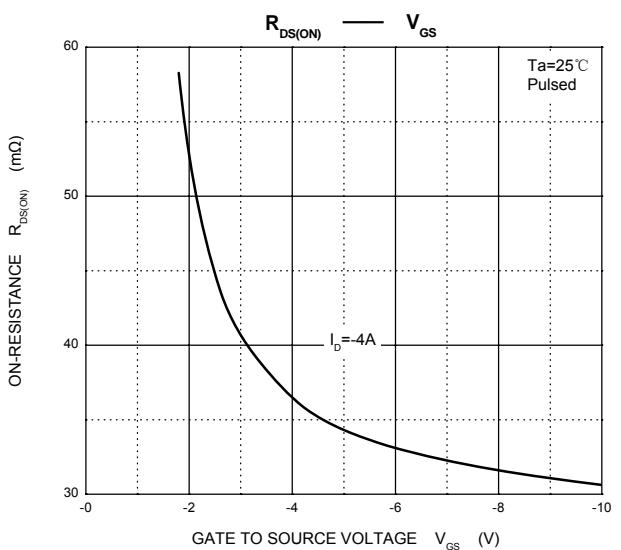
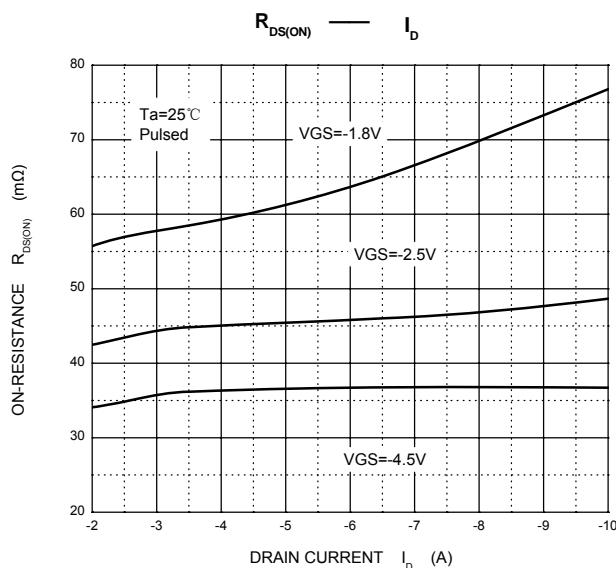
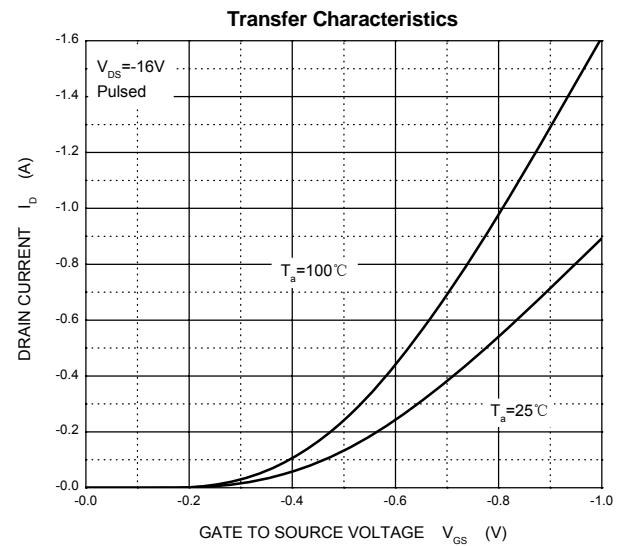
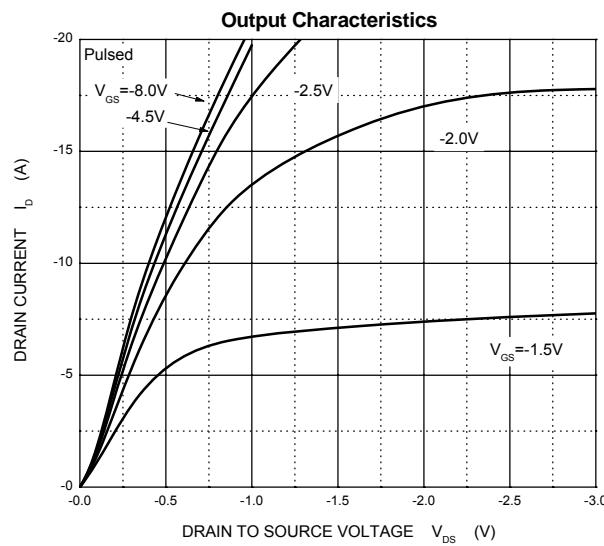
$T_a=25^\circ\text{C}$ unless otherwise specified

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|---|-----------------------------|---|------|-------|----------|------------------|
| Static Parameters | | | | | | |
| Drain-source breakdown voltage | $V_{(\text{BR})\text{DSS}}$ | $V_{GS} = 0V, I_D = -250\mu\text{A}$ | -20 | | | V |
| Gate threshold voltage (note2) | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = -250\mu\text{A}$ | -0.3 | -0.56 | -1 | |
| Gate-body leakage current | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 8V$ | | | ± 10 | μA |
| | | $V_{DS} = 0V, V_{GS} = \pm 4.5V$ | | | ± 1 | |
| Zero gate voltage drain current | I_{DSS} | $V_{DS} = -16V, V_{GS} = 0V$ | | | -1 | |
| Drain-source on-state resistance(note2) | $R_{DS(\text{on})}$ | $V_{GS} = -4.5V, I_D = -4A$ | | 37 | 50 | $\text{m}\Omega$ |
| | | $V_{GS} = -2.5V, I_D = -4A$ | | 45 | 60 | |
| | | $V_{GS} = -1.8V, I_D = -2A$ | | 56 | 73 | |
| Forward transconductance(note2) | g_{FS} | $V_{DS} = -5V, I_D = -4A$ | 8 | 16 | | S |
| Dynamic Parameters (note3) | | | | | | |
| Input capacitance | C_{iss} | $V_{DS} = -10V, V_{GS} = 0V, f = 1\text{MHz}$ | | 1450 | | pF |
| Output capacitance | C_{oss} | | | 205 | | |
| Reverse transfer capacitance | C_{rss} | | | 160 | | |
| Switching Parameters(note3)* | | | | | | |
| Total gate charge | Q_g | $V_{DS} = -10V, V_{GS} = -4.5V, I_D = -4A$ | | 17.2 | | nC |
| Gate-Source charge | Q_{gs} | | | 1.3 | | |
| Gate-drain charge | Q_{gd} | | | 4.5 | | |
| Turn-on delay time | $t_{d(\text{on})}$ | $V_{DS} = -10V, V_{GS} = -4.5V$ $R_{\text{GEN}} = 3\Omega, R_L = 2.5\Omega,$ | | 9.5 | | ns |
| Turn-on rise time | t_r | | | 17 | | |
| Turn-off delay time | $t_{d(\text{off})}$ | | | 94 | | |
| Turn-off fall time | t_f | | | 35 | | |
| Drain-Source Diode Characteristics | | | | | | |
| Drain-source diode forward voltage(note2) | V_{DS} | $V_{GS} = 0V, I_S = -1A$ | | | -1 | V |
| Maximum continuous drain-source diode forward current | I_S | | | | -4 | A |

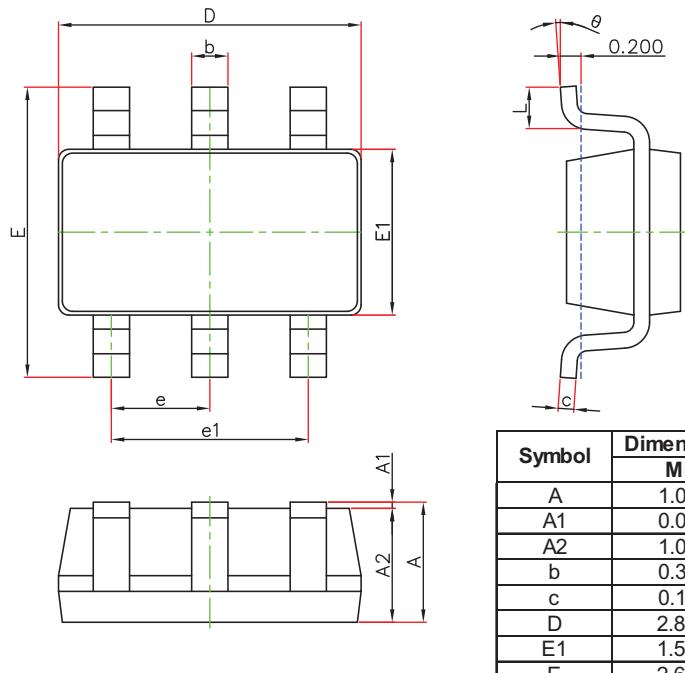
Notes:

1. Repetitive rating,pulse width limited by junction temperature.
2. Pulse Test : Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
3. These parameters have no way to verify.

Typical Characteristics

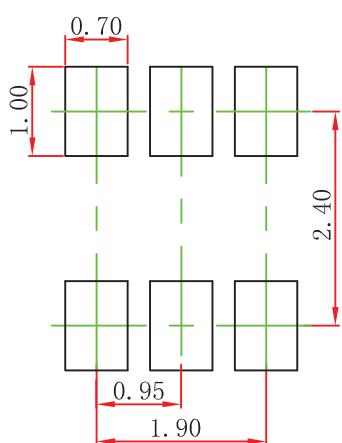


SOT-23-6L Package Outline Dimensions



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.111 | 0.119 |
| E1 | 1.500 | 1.700 | 0.059 | 0.067 |
| E | 2.650 | 2.950 | 0.104 | 0.116 |
| e | 0.950(BSC) | | 0.037(BSC) | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |

SOT-23-6L Suggested Pad Layout



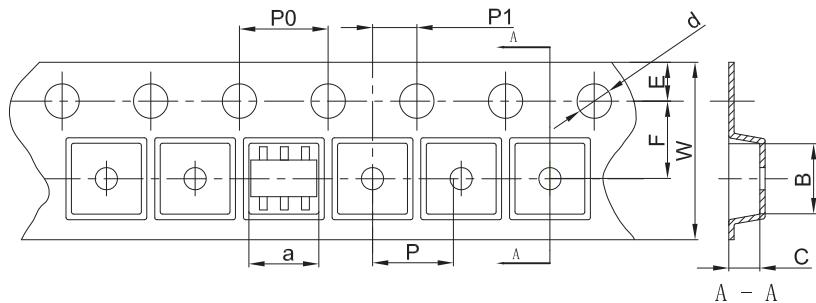
Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.

NOTICE

JCET reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JCET does not assume any liability arising out of the application or use of any product described herein.

SOT-23-6L Tape and Reel

SOT-23-6L Embossed Carrier Tape

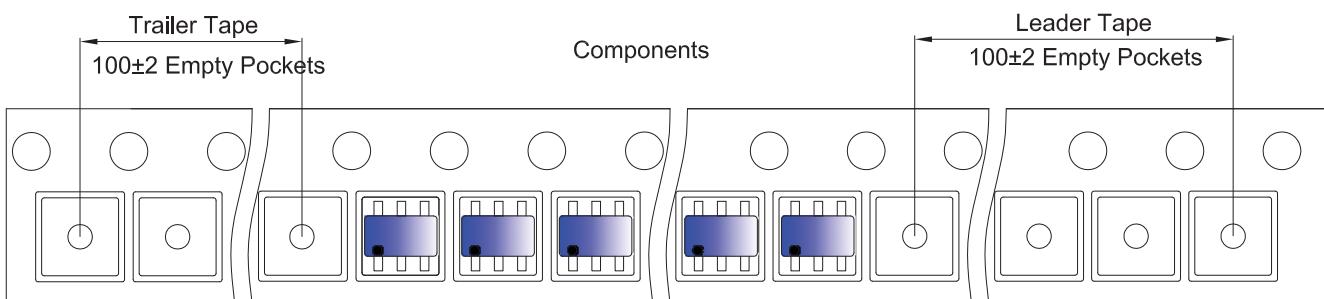


Packaging Description:

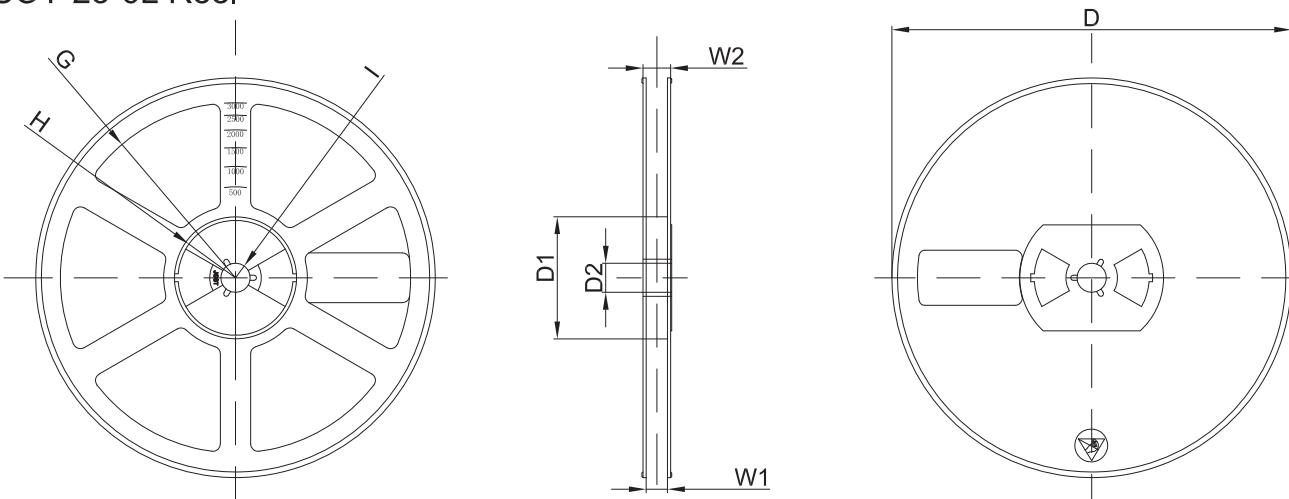
SOT-23-6L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 18.0cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

| Dimensions are in millimeter | | | | | | | | | | |
|------------------------------|------|------|------|-------|------|------|------|------|------|------|
| Pkg type | a | B | C | d | E | F | P0 | P | P1 | W |
| SOT-23-6L | 3.17 | 3.23 | 1.37 | Ø1.55 | 1.75 | 3.50 | 4.00 | 4.00 | 2.00 | 8.00 |

SOT-23-6L Tape Leader and Trailer



SOT-23-6L Reel



| Dimensions are in millimeter | | | | | | | | |
|------------------------------|---------|-------|-------|--------|--------|-------|------|-------|
| Reel Option | D | D1 | D2 | G | H | I | W1 | W2 |
| 7"Dia | Ø180.00 | 60.00 | 13.00 | R78.00 | R25.60 | R6.50 | 9.50 | 13.10 |

| REEL | Reel Size | Box | Box Size(mm) | Carton | Carton Size(mm) | G.W.(kg) |
|----------|-----------|------------|--------------|-------------|-----------------|----------|
| 3000 pcs | 7 inch | 30,000 pcs | 203×203×195 | 120,000 pcs | 438×438×220 | |